BCM120S05D3

Silicon Carbide Schottky Diode

1200V, 5A



Description

BCM120S05D3 utilizes Bestirpower's advanced silicon carbide diode technology. This technology combines the benefits of excellent low forward voltage and robustness. Consequently, the family is suitable for application requiring high power efficiency

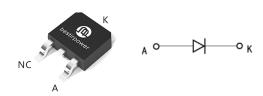
Applications

- Power factor correction(PFC)
- Solar inverter
- Uninterruptible power supply
- Motor drives
- Photo-voltaic inverter
- Electric car and charger

Features

V_{RRM}	I _F	$T_{J,max}$	Qc	
1200 V	5 A	175 ℃	27nC	

- Positive temperature coefficient
- Temperature-independent switching
- Maximum working temperature at 175 °C
- Unipolar devices and zero reverse recovery current
- Zero fo ward recovery current
- Essentially no switching losses
- Reduction of heat sink requirements
- High-frequency operation
- Reduction of EMI







Absolute Maximum Ratings (T_C = 25°C unless otherwise noted)

Symbol	Parameter	Value	Unit	
V _{RRM}	Repetitive Peak Reverse Voltage	1200	V	
I _F	Forward Current $T_C = 25^{\circ}C$		13	А
		T _C = 137°C	7	А
		T _C = 148°C	5	А
I _{F,SM}	Non-Repetitive Forward Surge Current	$T_C = 25$ °C, $t_p = 10$ ms	40	Α
		$T_C = 110^{\circ}C$, $t_p = 10 \text{ ms}$	34	А
l ² dt value	∫l²t	$T_C = 25^{\circ}C$, $t_p = 10 \text{ ms}$	12.5	A ² s
P _{tot}	Power Dissipation	T _C = 25°C	58	W
		T _C = 110°C	25	W
T_{J} , T_{STG}	Operating Junction and Storage Temperature		-55 to +175	°C



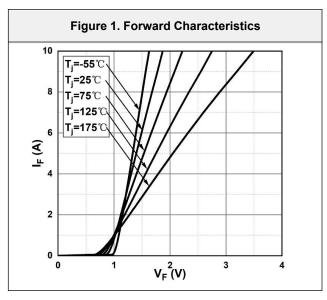
Thermal Characteristics

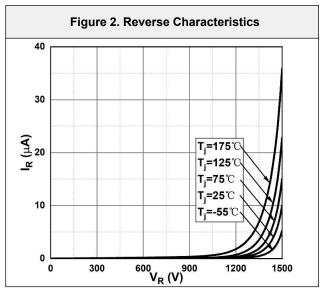
Symbol	Parameter	Value	Unit
Rec	Thermal Resistance, Junction to Case, Typ.	2.6	°C/W

Electrical Characteristics (T_C = 25°C unless otherwise noted)

Symbol	Parameter	Test Conditions		Тур	Max	Unit	
V _{DC}	DC blocking voltage		1200	-	-	V	
V _F	Forward Voltage	I _F =5A , T _C = 25°C		1.37	1.8		
		l _F =5A,Tc=175℃	-	1.8	-	V	
I _R Reverse Current	D 0 1	V _R = 1200 V, T _C = 25°C	-	0.5	16		
	Reverse Current	V _R = 1200 V, T _C = 175°C	-	8	-	μA	
Qc	Total Capacitive Charge	VR=800V, Tj=25°C , QC=∫0 VRC(V)dV		27	-	nC	
С	Total capacitance	VR=0V, f=1MHZ	-	377	-	pF	
		V _R =400V, f=1MHZ	-	25	-		
		VR=800V, f=1MHZ	-	19	-		
Ec	Capacitance Stored Energy	V _R =800V		6.8	-	μJ	

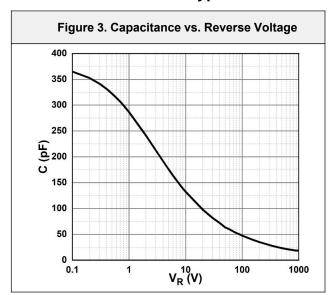
Typical Performance Characteristics

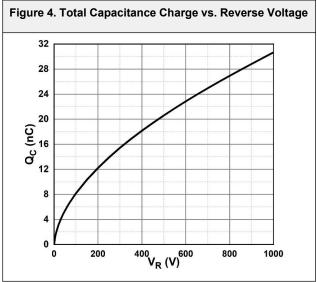


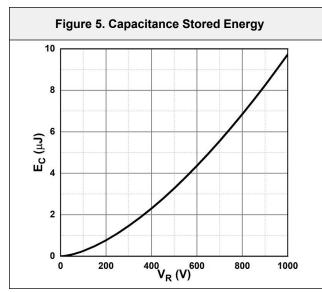


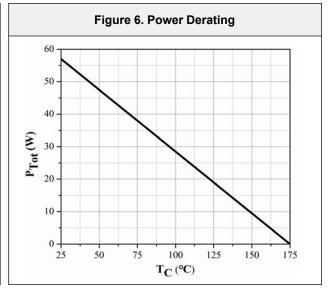


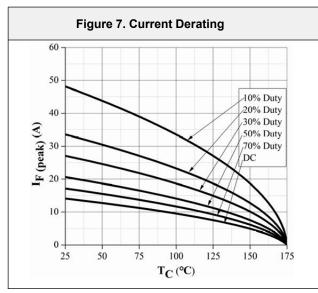
Typical Performance Characteristics

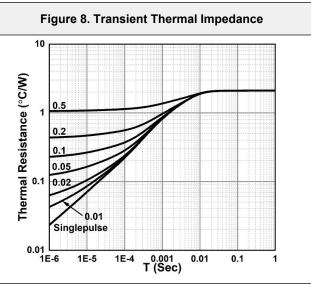








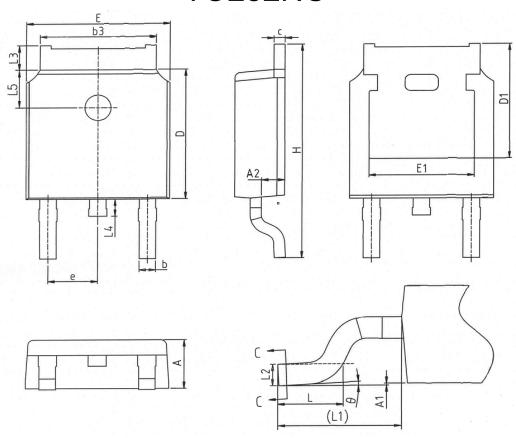






Package Outlines

TO252NC



COMMON DIMENSIONS

SYMBOL	mm				
SIMBUL	MIN	NOM	MAX		
A	2. 20	2.30	2.38		
A1	0.00	-	0.12		
A2	0.97	1.07	1. 17		
b	0.68	0.78	0.90		
b3	5. 20	5. 33	5. 46		
с	0.43	0.61			
D	5. 98 6. 10 6. 23				
D1		5. 30REF			
E	6. 40	6. 60	6. 73		
E1	4.63	4.63			
е		2. 286BSC			
Н	9.40	9. 40 10. 10 10. 50			
L	1.38 1.50 1.75				
L1	2. 90REF				
L2	0. 51BSC				
L3	0.88	-	1.28		
L4	0.50	-	1.00		
L5	1.65	1.80	1.95		
θ	0° - 8°				

^{*} Dimensions in millimeters



Package Marking and Ordering Information

Part Number	Top Marking	Package	Packing Method	Reel Size	Tape Width	Quantity
BCM120S05D3	BCM120S05D3	TO252NC	Tape & Reel	330 mm	16 mm	2500 units

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